

EH163-M



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Overview

Apacer EH163-M is a super speed USB 3.1 GEN 1 flash disk drive (backward compatible with USB 2.0/1.1) and featuring plug-and-play, EH163-M can be easily adopted in any computing system with an available USB port. The device can be automatically detected by the host computer so that users can access data to read, write, copy, or move data between host system drive and EH163-M. Data security-wise, EH163-M is built with the highest durability and ruggedness with a special Chip-On-Board (COB) packaging technology, which allows your precious files to be safely stored and protected against dust, water and shock at all times.



Moreover, With the high reliable MLC NAND Flash in a fixed BOM, it's tailor-made for embedded and industrial applications, such as medical, IPC and automation applications.

Feature

- · USB 3.1 Gen1 high-speed transmission
- · Support S.M.A.R.T Function
- · Chip-On-Board technology: water/moisture resistance, dust, and shock resistant
- · Implements advanced wear-leveling algorithms
- · ECC engine
- · Power Saving implemented

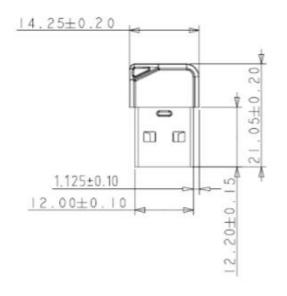
Apacer

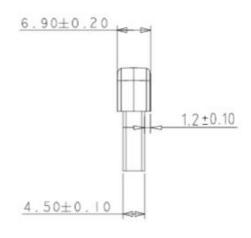
Specifications

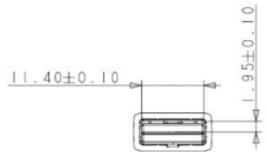
Model EH163-M Interface USB 3.1 Gen1 Connector USB 3.0 A Type Plug Form Factor USB flash drive Operation Mode NULL NAND Flash Type MLC Capacity 8GB~64GB Sustained Read Performance (MB/sec) Up to 225 Sustained Write Performance (MB/sec) Up to 80 ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) 0 ~ + 70 Storage Temperature (°C) -25 ~ + 85 Vibration Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA Dimension (L x W x H) 23.1 x 14.25 x 6.9		
Connector USB 3.0 A Type Plug Form Factor USB flash drive Operation Mode NULL Transfer Mode NULL NAND Flash Type MLC Capacity 8GB~64GB Sustained Read Performance (MB/sec) Up to 225 Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Model	EH163-M
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Transfer Mode NAND Flash Type MLC Capacity 8GB~64GB Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) O ~ + 70 Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Form Factor	USB flash drive
NAND Flash Type Capacity 8GB~64GB Sustained Read Performance (MB/sec) Up to 225 Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) O ~ + 70 Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Operation Mode	NULL
Capacity Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Transfer Mode	NULL
Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) Storage Temperature (°C) O ~ + 70 -25 ~ + 85 Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	NAND Flash Type	MLC
Sustained Write Performance (MB/sec) ECC Engine Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) O ~ + 70 Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Capacity	8GB~64GB
Built-in 39-bit per 1K bytes BCH ECC Standard Operating Temperature (°C) Storage Temperature (°C) O ~ + 70 -25 ~ + 85 Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Sustained Read Performance (MB/sec)	Up to 225
Standard Operating Temperature (°C) O ~ + 70 -25 ~ + 85 Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Sustained Write Performance (MB/sec)	Up to 80
Storage Temperature (°C) Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Active mode: 190 mA & Idle mode: 45 mA	ECC Engine	Built-in 39-bit per 1K bytes BCH ECC
Operation: 7.69 Grms, 20~2000 Hz/random (comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Active mode: 190 mA & Idle mode: 45 mA	Standard Operating Temperature (°C)	0 ~ + 70
(comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random (comply with MIL-STD-810G) Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Storage Temperature (°C)	-25 ~ + 85
Power Consumption Active mode: 190 mA & Idle mode: 45 mA	Vibration	(comply with MIL-STD-810G) Non-operating: 4.02(Grms), 15~2000(Hz)/random
	Operating Voltage	5.0 V ± 5%
Dimension (L x W x H) 23.1 x 14.25 x 6.9	Power Consumption	Active mode: 190 mA & Idle mode: 45 mA
	Dimension (L x W x H)	23.1 x 14.25 x 6.9
MTBF (hours) >1,000,000	MTBF (hours)	>1,000,000

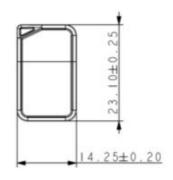
Apacer

Mechanical Specification









Unit: mm

For more information, contact your Apacer representative

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